

Description

[MULTI-CHIP PACKAGE]

CROSS REFERENCE TO RELATED APPLICATIONS

[0001] This application claims the priority benefit of Taiwan application serial no. 92120188, filed July 24, 2003.

BACKGROUND OF INVENTION

[0002] Field of the Invention

[0003] The present invention relates to a multi-chip package structure. More particularly, the present invention relates to a multi-chip package structure having a plurality of flip chips stacked over a substrate carrier, capable of improving electrical performance of the substrate and reducing area occupation of the multi-chip package.

[0004] Description of the Related Art

[0005] In this information-base society, electronic products has become an indispensable tool serving us in many ways all around the clock. As electronic technologies continue to progress, many multi-functional and fast computing elec-

tronic products with a large memory storage capacity have been developed. These products are not only more powerful than the previous generation, but also increasingly light and compact as well. To reduce weight and volume of a package, the concept of integration must be incorporated into the design of integrated circuits. Since the fabrication of integrated circuits with nanometric features is now possible, many functions can be incorporated within a tiny chip.

[0006] To increase chip package function without increasing size, semiconductor manufacturers have developed several highly compact type of packages including the multi-chip module, the chip-scale package and the stacked multi-chip package. Fig. 1 is a schematic cross-sectional view of a conventional stacked multi-chip package structure.

[0007] As shown in Fig. 1, a conventional stacked multi-chip package 100 comprises a first chip 110, a second chip 120, a substrate 130, a plurality of bumps 140, 142, some insulating material 150 and a plurality of solder balls 160. The first chip 110 has a plurality of bonding pads 112, 116 on an active surface 114. The second chip 120 similarly has a plurality of bonding pads 122 on an active surface 124. The first chip 110 and the second chip

120 are electrically connected through the bumps 140. One end of each bump 140 is bonded to one of the bonding pads 112 of the first chip 110. The other end of the bump 140 is bonded to a corresponding bonding pad 124 on the second chip 120. The active surface 114 of the first chip 110 faces the active surface 124 of the second chip 120. The substrate 130 has a through opening 132 capable of accommodating the entire second chip 120. Furthermore, the substrate 230 has a plurality of bonding pads 134, 135 on an upper surface 136 and a lower surface 137. The bonding pads 134 are positioned around the peripheral region of the opening 132. The first chip 110 and the substrate 130 are joined together through the bumps 142. One end of each bump 142 is bonded to one of the bonding pads 116 of the first chip 110. The other end of the bump 142 is bonded to a corresponding bonding pad 134 of the substrate 130. The solder balls 160 are attached to the respective bonding pads 135 of the substrate 130. The insulating material 150 is deposited within the opening 132 to enclose the bumps 140 and the second chip 120.

[0008] In the aforementioned multi-chip package 100, the opening 132 must be fabricated in the substrate 130 to ac-

commodate the second chip 120. Moreover, circuit wires have to be routed around the opening 132, causing the increase of the overall signal transmission length. This setup not only lowers the electrical performance of the substrate 130, but also complicates the manufacturing process and increases the production cost. Meanwhile, the outer perimeter of the substrate 130 have to increase, thus leading to some difficulties in reducing overall size of the multi-chip package 100.

SUMMARY OF INVENTION

- [0009] Accordingly, at least one object of the present invention is to provide a multi-chip package structure capable of improving the electrical performance of the substrate inside the package.
- [0010] At least a second object of this invention is to provide a multi-chip package structure capable of lowering the production cost of the substrate inside the package.
- [0011] At least a third object of this invention is to provide a multi-chip package structure capable of reducing surface area of the multi-chip package.
- [0012] To achieve these and other advantages and in accordance with the purpose of the invention, as embodied and broadly described herein, the invention provides a multi-

chip package structure. The multi-chip package structure at least comprises a first chip, a second chip, a plurality of first bumps and a plurality of contacts. The first chip has an active surface. The second chip is mounted over the active surface of the first chip. The height of the second chip in a direction perpendicular to the active surface of the first chip or the thickness of the second chip is h_1 . The first bumps are positioned between the active surface of the first chip and the second chip. The height of each bump in a direction perpendicular to the active surface of the first chip is h_2 . The contacts protrude from the active surface of the first chip and the height of each contact in a direction perpendicular to the active surface of the first chip is h_3 . Finally, the relation between the values of h_1 , h_2 and h_3 can be represented by an inequality: $h_3 \geq h_1 + h_2$.

[0013] The first chip is suited to be mounted onto a substrate through the contacts. The second chip is positioned between the first chip and the substrate due to $h_3 \geq h_1 + h_2$. Therefore, the entire substrate can now be used for circuit layout and the average length of signal transmission pathways within the multi-chip package is reduced. Hence, electrical performance of the substrate is improved

and the production cost of the substrate is reduced. Furthermore, there is no opening or cavity in the substrate compared to the above conventional multi-chip package, the outer perimeter and the surface area of the substrate can be reduced. In other words, a smaller multi-chip package structure can be produced.

[0014] It is to be understood that both the foregoing general description and the following detailed description are exemplary, and are intended to provide further explanation of the invention as claimed.

BRIEF DESCRIPTION OF DRAWINGS

[0015] The accompanying drawings are included to provide a further understanding of the invention, and are incorporated in and constitute a part of this specification. The drawings illustrate embodiments of the invention and, together with the description, serve to explain the principles of the invention.

[0016] Fig. 1 is a schematic cross-sectional view of a conventional stacked multi-chip package structure.

[0017] Fig. 2 is a schematic cross-sectional view of a multi-chip package structure according to a first preferred embodiment of this invention.

[0018] Fig. 3 is a top view showing the multi-chip package ac-

cording to the first preferred embodiment of this invention.

[0019] Fig. 4 is a top view showing a multi-chip package according to a second preferred embodiment of this invention.

[0020] Fig. 5 is a cross-sectional view of a multi-chip package according to a third preferred embodiment of this invention.

[0021] Fig. 6 is a top view showing the multi-chip package according to the third preferred embodiment of this invention.

[0022] Fig. 7 is a cross-sectional view of a multi-chip package according to a fourth preferred embodiment of this invention.

[0023] Fig. 8 is a cross-sectional view of a multi-chip package according to a fifth preferred embodiment of this invention.

DETAILED DESCRIPTION

[0024] References will now be made in detail to the present preferred embodiments of the invention, examples of which are illustrated in the accompanying drawings. Wherever possible, the same reference numbers are used in the drawings and the description to refer to the same or like parts.

[0025] Fig. 2 is a schematic cross-sectional view of a multi-chip package structure according to a first preferred embodiment of this invention. Fig. 3 is a top view showing the multi-chip package according to the first preferred embodiment of this invention. The multi-chip package structure 200 comprises a first chip 210, a second chip 220, a substrate 230, a plurality of bumps 240, a plurality of contacts 250, some insulating material 260 and a plurality of solder balls 270. The first chip 210 has a plurality of bonding pads 212, 214 on an active surface 216. The second chip 220 also has a plurality of bonding pads 222 on an active surface 224. The first chip 210 and the second chip 220 are electrically connected via the bumps 240 (labeled 1 in Fig. 3).

[0026] To fabricate the bumps 240, a wire-bonding machine (not shown) is deployed to form stud bumps on the bonding pads 222 of the second chip 220. Thereafter, an underfill film 260 made from an insulating material is formed over the active surface 224 of the second chip 220. The underfill film 260 exposes the top surface of the bumps 240 to produce a package module 229 that can be electrically tested independently. The package module 229 has a chip-scale package (CSP) configuration, for example. In

this embodiment, the package module 229 comprises the second chip 220, the bumps 240 and the underfill film 260. After performing an electrical test on the package module 229 to confirm its electrical performance, the package module 229 is mounted on the first chip 210. A screen printing method can be one of the ways to deposit solder material 280 on the bonding pads 212 of the first chip 210. The package module 229 is positioned over the first chip 210 such that the bumps 240 are in contact with the solder material 280 over the bonding pads 212. A re-flow process is carried out to join the bumps 240 to the respective bonding pads 212 on the first chip 210 via the solder material 280. Hence, the second chip 220 is electrically connected to the first chip 210 through the bumps 240 and the solder material 280.

[0027] However, the method of joining the bumps 240 with the bonding pads 212 is not limited to the aforementioned process. For example, a thermal-sonic bonding may be used to bond the bumps 240 directly to the respective bonding pads 212 on the first chip 210 after checking the electrical performance of the package module 229. Thereafter, the underfill film 260 is thermally cured to fill the space between the first chip 210 and the second chip 220.

[0028] The substrate 230 has a plurality of bonding pads 232, 234 on an upper surface 236 and a lower surface 238 respectively. The first chip 210 is electrically connected to the substrate 230 via contacts (labeled 2 in Fig. 3). Each contact 250 can comprise a pair of stacked bumps 252 and 254.

[0029] In this embodiment, the stacked bumps 252, 254 are manufactured by using a wire bonding machine. First, the wire-bonding machine is deployed to form stud bumps 252 on the bonding pads 214 of the first chip 210 by stamping. Next, the wire-bonding machine is again deployed to form stud bumps 254 on top of the respective stud bumps 252. Thereafter, an underfill film 261 made from an insulating material is formed over the active surface 216 of the first chip 210. The underfill film 261 exposes the top surface of the contacts 250 to produce a package module 219 that can be electrically tested independently. Furthermore, the underfill film 261 has an opening 263 in the middle, capable of accommodating the package module 229.

[0030] In this embodiment, the package module 219 comprises the package module 229, the first chip 210, the contacts 250 and the underfill film 261. After testing the electricity

of the package module 219, the package module 219 is mounted on the substrate 230. A screen printing method can be one of the ways to deposit solder material 282 on the bonding pads 232 of the substrate 230. The package module 219 is positioned over the substrate 230 such that the contacts 250 are in contact with the solder material 282 over the bonding pads 232. A reflow process is carried out to join the contacts 250 to the respective bonding pads 232 on the substrate 230 via the solder material 282. Hence, the first chip 210 is electrically connected to the substrate 230 through the contacts 250 and the solder material 282. However, the method of joining the contacts 250 with the bonding pads 232 is not limited to the aforementioned process. For example, a thermal-sonic bonding may be used to bond the contacts 250 directly to the respective bonding pads 232 on the substrate 230 after checking the electrical performance of the package module 219. Thereafter, the underfill film 261 is thermally cured to fill the space between the first chip 210 and the substrate 230.

[0031] As shown in Figs. 2 and 3, the second chip 220 is sandwiched between the first chip 210 and the substrate 230. Furthermore, the second chip 220 is located within the

active surface 216 of the first chip 210. Both underfill films 260 and 261 are located on the active surface 216 of the first chip 210 to enclose the bumps 240 and the contacts 250. The solder balls 270 are attached to the bonding pads 234 on the under surface 238 of the substrate 230.

[0032] In Fig. 2, the height of the second chip 220 in a direction perpendicular to the active surface 216 of the first chip 210 is defined as h_1 . The height of the bump 240 in a direction perpendicular to the active surface 216 of the first chip 210 is defined as h_2 . The height of the contact 250 in a direction perpendicular to the active surface 216 of the first chip 210 is defined as h_3 . The values of h_1 , h_2 and h_3 are related by the inequality: $h_3 \geq h_2 + h_1$. In addition, if the distance between the substrate 230 and the active surface 216 of the first chip 210 is defined as d , the values of d , h_1 and h_2 are related by the inequality: $d \geq h_1 + h_2$.

[0033] In this embodiment, the second chip 220 is positioned between the first chip 210 and the substrate 230. Since there is no need to form an opening in the substrate 230 as in a conventional multi-chip package design, a complete internal circuit wiring space is maintained. This de-

sign not only reduces the average length of transmission pathways to improve electrical performance, but also simplifies the process of manufacturing the substrate 230. Moreover, the perimeter of the substrate 230 can be reduced leading to a smaller area occupation for the multi-chip package 200. Furthermore, the electrical testing of the package module 229 before joining to the first chip 210 and the electrical testing of the package module 219 before joining to the substrate 230 are performed to ensure the performance and yield of the multi-chip package.

[0034] The multi-chip package in aforementioned embodiment has contacts formed by stacking two bumps. However, more bumps may be stacked to increase the overall height level of the contacts. For example, three, four or some other number of bumps may be stacked on top of each other to produce higher contacts.

[0035] Fig. 4 is a top view showing a multi-chip package according to a second preferred embodiment of this invention. The multi-chip package structure according to the second embodiment is an extension to the first embodiment. Similarly, the second chip 320 is located between the first chip 310 and the substrate 330. The first chip 310 is electrically connected to the second chip 320 via bumps 340

(labeled 1 in Fig. 4). The first chip 310 is electrically connected to the substrate 330 via contacts 350 (labeled 2 in Fig. 4). The height of the contacts 350 is greater than the combination of the thickness of second chip 320 and the height of the bump 340. Hence, unlike the conventional design, the substrate 330 has no opening or cavity to reduce wiring space inside the multi-chip package. One major difference of the second embodiment from the first embodiment is that both the first chip 310 and the second chip 320 are rectangular with the first chip 310 extending in a direction perpendicular to the second chip 320. Moreover, the second chip 320 extends over areas outside the active surface of the first chip 310.

[0036] Fig. 5 is a cross-sectional view of a multi-chip package according to a third preferred embodiment of this invention. Fig. 6 is a top view showing the multi-chip package according to the third preferred embodiment of this invention. The third embodiment is an extension of the first embodiment of this invention. As shown in Figs. 5 and 6, a second chip 420 and a third chip 430 are set up over an active surface 412 of a first chip 410. The second chip 420 is electrically connected to the first chip 410 via bumps 440 (labeled 1 in Fig. 6). The third chip 430 is

electrically connected to the first chip 410 via bumps 450 (labeled 2 in Fig. 6). The first chip 410 is electrically connected to a substrate 470 via contacts 460 (labeled 3 in Fig. 6). Each contact 460 comprises a pair of stacked bumps 462 and 464. The stacked bumps 462 and 464 are formed, for example, by stamping via a wire-bonding machine.

[0037] After fabricating bumps 440 and bumps 450 over the second chip 420 and the third chip 430, package modules 429 and 439 having a chip-scale structure are formed. Before attaching the package modules 429 and 439 to the first chip 410, each of the package modules 429 and 439 is electrically tested to ensure good electrical performance. After mounting the package modules 429 and 439 and forming the contacts 460 on the first chip 410 to form a package module 419, the package module 419 is also electrically tested to ensure good electrical connection and performance. Thereafter, the package module 419 is attached to the substrate 470. Through the aforementioned electrical testing of the package modules 419, 429 and 439, ultimate yield of the multi-chip package 400 effectively increases.

[0038] In Fig. 5, the height of the second chip 420 in a direction

perpendicular to the active surface 412 of the first chip 410 is defined as h_1 . The height of the bump 440 in a direction perpendicular to the active surface 412 of the first chip 410 is defined as h_2 . The height of the contact 460 in a direction perpendicular to the active surface 412 of the first chip 410 is defined as h_3 . The height of the third chip 430 in a direction perpendicular to the active surface 412 of the first chip 410 is defined as h_4 . The height of the bump 450 in a direction perpendicular to the active surface 412 of the first chip 410 is defined as h_5 . The values of h_1 , h_2 , h_3 , h_4 and h_5 are related by the following inequalities: $h_3 \geq h_1 + h_2$, $h_3 \geq h_4 + h_5$. In addition, if the distance between the substrate 470 and the active surface 412 of the first chip 410 is defined as d , the values of d , h_1 , h_2 , h_4 and h_5 are related by the following inequalities: $d \geq h_1 + h_2$, $d \geq h_4 + h_5$. In this embodiment, the second chip 420 and the third chip 430 are sandwiched between the first chip 410 and the substrate 470. Hence, unlike a conventional design, the substrate 470 also has no opening to reduce wiring space inside the multi-chip package.

[0039] In the third embodiment, a pair of package modules 429 and 430 are enclosed within the space between the first

chip 410 and the substrate 470. In general, any number of package modules can be enclosed as long as there is sufficient space between the first chip 410 and the substrate 470.

[0040] In the aforementioned embodiments, the contacts are fabricated from a pair of stacked bumps. However, the number of stacked bumps for forming the contact is unrestricted. Fig. 7 is a cross-sectional view of a multi-chip package according to a fourth preferred embodiment of this invention. Since the multi-chip package structure in this embodiment is similar to the one in the first embodiment, detailed description of the identical portions are omitted. One aspect of this embodiment is that the contacts 550 are cylindrical metallic rods fabricated through a multi-layered printing method, for example.

[0041] The height of the second chip 520 in a direction perpendicular to the active surface 516 of the first chip 510 is defined as $h1$. The height of the bump 540 in a direction perpendicular to the active surface 516 of the first chip 510 is defined as $h2$. The height of the contact 550 in a direction perpendicular to the active surface 516 of the first chip 510 is defined as $h3$. The values of $h1$, $h2$ and $h3$ are related by the following inequality: $h3 \geq h1 + h2$.

In addition, if the distance between the substrate 530 and the active surface 516 of the first chip 510 is d , then the values of d , h_1 and h_2 are related by the inequality: $d \geq h_1 + h_2$.

[0042] In all the aforementioned embodiments, the package modules 229, 429, 439 on the chips 210 and 410 are chip-scale packages. However, the application of this invention is not restricted as such. Fig. 8 is a cross-sectional view of a multi-chip package according to a fifth preferred embodiment of this invention. The package module 620 mounted on the chip 610 in Fig. 8 can have a multi-chip module (MCM) or a system in package (SIP) structure. As shown in Fig. 8, the package module 620 comprises a module substrate 622, a pair of chips 630, 632, some packaging material 640 and a plurality of bumps 650. The module substrate 622 has a first surface 624 and a second surface 626. The chips 630, 632 are bonded to the first surface 624. The bumps 650 are attached to the second surface 626. The chip 630 is attached to the module substrate 622 as a flip chip via a plurality of module bumps 631. Gap-filling material 633 is inserted into the space between the chip 630 and the module substrate 622 to enclose the module bumps 631.

The chip 632 is electrically connected to the module substrate 622 via a plurality of wire-bonded conductive wires 634. The packaging material encloses the chips 630, 632 and the conductive wires 634. The entire package module 620 is bonded to the chip 610 via bumps 650.

[0043] Before joining the package module 620 to the chip 610, the package module 620 is electrically tested to ensure its electrical performance. After mounting the package module 620 onto the chip 610 to form a package module 619, the package module 619 is again tested to ensure its electrical performance. The entire package 619 is mounted on the substrate 670. Furthermore, an underfill film 680 is formed in the space between the chip 610 and the module substrate 622 so that the bumps 650 are enclosed. Similarly, another underfill film 681 is formed in the space between the chip 610 and the substrate 670 to enclose the contacts 660.

[0044] In the fifth embodiment, the package module 620 is in contact with the substrate 670 so that any heat generated by the module 620 can be conducted away via the substrate 670. In other words, the heat-dissipating capacity of the package module 620 effectively increases. However, the package module 620 needs not to contact the sub-

strate 670. In addition, the package module 620 may include more than two chips.

[0045] In addition, cylindrical metallic rods or posts serve as contacts 660 inside the multi-chip package. However, the contacts 660 can be stacked bumps attached to the bonding pads 612 of the chip 610 with a wire-bonding machine similar to the one deployed according to the first embodiment of this invention.

[0046] If the height of the package module 620 in a direction perpendicular to the active surface 616 of the chip 610 is h_1 and the distance from the substrate 670 to the active surface 616 of the chip 610 is d , then the values of d and h_1 are related by the inequality: $d \geq h_1$.

[0047] In summary, several advantages of this invention include:

[0048] 1. The substrate inside the multi-chip package is free of any through opening or cavity so that the average length of signal transmission pathways is reduced and the electrical performance of the substrate is improved.

[0049] 2. Because forming a through opening or cavity in the substrate for accommodating a chip renders unnecessary, the process of manufacturing the substrate is simplified and the cost of producing the multi-chip package is reduced.

[0050] 3. In the absence of a through opening or cavity in the substrate for accommodating a chip, the entire substrate can be used for accommodating circuit wires so that overall level of integration effectively increases. Thus, the perimeter of the substrate can be reduced and a multi-chip package occupying a smaller area can be produced.

[0051] 4. Because the package modules are independently tested before assembling, overall yield of the multi-chip package effectively increases.

[0052] It will be apparent to those skilled in the art that various modifications and variations can be made to the structure of the present invention without departing from the scope or spirit of the invention. In view of the foregoing, it is intended that the present invention cover modifications and variations of this invention provided they fall within the scope of the following claims and their equivalents.